



TXS0206A SD Card Voltage-Translation Transceiver

1 Features

- Level Translator
 - V_{CCA} and V_{CCB} Range of 1.1 V to 3.6 V
 - Fast Propagation Delay (4.4 ns Maximum When Translating Between 1.8 V and 3 V)
- ESD Protection Exceeds JESD 22
 - 2500-V Human-Body Model (A114-B)
 - 250-V Machine Model (A115-A)
 - 1500-V Charged-Device Model (C101)

2 Applications

- Mobile Phones
- Tablet PCs
- Notebooks
- Ultrabook Computers

3 Description

The TXS0206A is a level shifter for interfacing microprocessors with MultiMediaCards (MMCs), secure digital (SD) cards, and Memory Stick™ cards.

The voltage-level translator has two supply voltage pins. V_{CCA} as well as V_{CCB} can be operated over the full range of 1.1 V to 3.6 V. The TXS0206A enables system designers to easily interface applications processors or digital basebands to memory cards and SDIO peripherals operating at a different I/O voltage level.

The TXS0206A is offered in a 20-bump wafer chip scale package (WCSP). This package has dimensions of 1.96 mm × 1.56 mm, with a 0.4-mm ball pitch for effective board-space savings. Memory cards are widely used in mobile phones, PDAs, digital cameras, personal media players, camcorders, set-top boxes, etc. Low static power consumption and small package size make the TXS0206A an ideal choice for these applications.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE
TXS0206A	DSBGA (20)	1.96 mm × 1.56 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Application Example

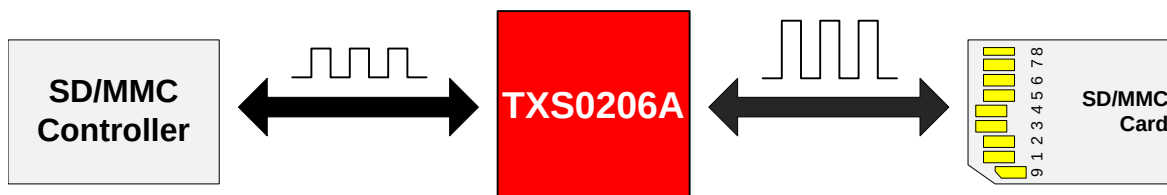


Table of Contents

1 Features	1	7 Parameter Measurement Information	15
2 Applications	1	8 Detailed Description	16
3 Description	1	8.1 Overview	16
4 Revision History	2	8.2 Functional Block Diagram	16
5 Pin Configuration and Functions	3	8.3 Feature Description	17
6 Specifications	4	8.4 Device Functional Modes	18
6.1 Absolute Maximum Ratings	4	9 Application and Implementation	19
6.2 ESD Ratings	4	9.1 Application Information	19
6.3 Recommended Operating Conditions	5	9.2 Typical Application	19
6.4 Thermal Information	6	9.3 System Examples	21
6.5 Electrical Characteristics	6	10 Power Supply Recommendations	22
6.6 Timing Requirements— $V_{CCA} = 1.2\text{ V} \pm 0.1\text{ V}$	7	11 Layout	22
6.7 Timing Requirements— $V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$	8	11.1 Layout Guidelines	22
6.8 Timing Requirements— $V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$	8	11.2 Layout Example	23
6.9 Switching Characteristics— $V_{CCA} = 1.2\text{ V} \pm 0.1\text{ V}$	9	12 Device and Documentation Support	24
6.10 Switching Characteristics— $V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$	10	12.1 Documentation Support	24
6.11 Switching Characteristics— $V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$..	11	12.2 Community Resources	24
6.12 Operating Characteristics — $V_{CCA} = 1.2\text{ V}$	12	12.3 Trademarks	24
6.13 Operating Characteristics — $V_{CCA} = 1.8\text{ V}$	13	12.4 Electrostatic Discharge Caution	24
6.14 Operating Characteristics — $V_{CCA} = 3.3\text{ V}$	13	12.5 Glossary	24
6.15 Typical Characteristics	14	13 Mechanical, Packaging, and Orderable Information	24

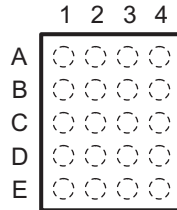
4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (May 2012) to Revision B	Page
• Added <i>Device Information</i> table, <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section.	1
• Deleted the ordering information. See POA at the end of the datasheet.....	1

5 Pin Configuration and Functions

**YFP Package
20-Pin DSBGA
Top View**



Pin Assignments

	1	2	3	4
A	DAT2A	V _{CCA}	WP	DAT2B
B	DAT3A	CD	V _{CCB}	DAT3B
C	CMDA	GND	GND	CMDB
D	DAT0A	CLKA	CLKB	DAT0B
E	DAT1A	CLK-f	EN	DAT1B

Pin Functions

PIN		TYPE	DESCRIPTION
NO.	NAME		
A1	DAT2A	I/O	Data bit 2 connected to host. Referenced to V _{CCA} . Includes a 40-kΩ pullup resistor to V _{CCA} .
A2	V _{CCA}	Pwr	A-port supply voltage. V _{CCA} powers all A-port I/Os and control inputs.
A3	WP	O	Connected to write protect on the mechanical connector. The WP pin has an internal 100-kΩ (± 30%) pullup resistor to V _{CCA} . Leave unconnected if not used.
A4	DAT2B	I/O	Data bit 2 connected to memory card. Referenced to V _{CCB} . Includes a 40-kΩ pullup resistor to V _{CCB} .
B1	DAT3A	I/O	Data bit 3 connected to host. Referenced to V _{CCA} . Includes a 40-kΩ pullup resistor to V _{CCA} .
B2	CD	O	Connected to card detect on the mechanical connector. The CD pin has an internal 100-kΩ (± 30%) pullup resistor to V _{CCA} . Leave unconnected if not used.
B3	V _{CCB}	Pwr	B-port supply voltage. V _{CCB} powers all B-port I/Os.
B4	DAT3B	I/O	Data bit 3 connected to memory card. Referenced to V _{CCB} . Includes a 40-kΩ pullup resistor to V _{CCB} .
C1	CMDA	I/O	Command bit connected to host. Referenced to V _{CCA} . Includes a 40-kΩ pullup resistor to V _{CCA} .
C2	GND	—	Ground
C3	GND	—	Ground
C4	CMDB	I/O	Command bit connected to memory card. Referenced to V _{CCB} . Includes a 40-kΩ pullup resistor to V _{CCB} .
D1	DAT0A	I/O	Data bit 0 connected to host. Referenced to V _{CCA} . Includes a 40-kΩ pullup resistor to V _{CCA} .
D2	CLKA	I	Clock signal connected to host. Referenced to V _{CCA} .
D3	CLKB	O	Clock signal connected to memory card. Referenced to V _{CCB} .
D4	DAT0B	I/O	Data bit 0 connected to memory card. Referenced to V _{CCB} . Includes a 40-kΩ pullup resistor to V _{CCB} .
E1	DAT1A	I/O	Data bit 1 connected to host. Referenced to V _{CCA} . Includes a 40-kΩ pullup resistor to V _{CCA} .
E2	CLK-f	O	Clock feedback to host for resynchronizing data to a processor. Leave unconnected if not used.
E3	EN	I	Enable/disable control. Pull EN low to place all outputs in Hi-Z state. Referenced to V _{CCA} .
E4	DAT1B	I/O	Data bit 1 connected to memory card. Referenced to V _{CCB} . Includes a 40-kΩ pullup resistor to V _{CCB} .

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CCA}	Supply voltage, A-Port		−0.5	4.6	V
V _{CCB}	Supply voltage, B-Port		−0.5	4.6	V
V _I	Input voltage	I/O ports (A port)	−0.5	4.6	V
		I/O ports (B port)	−0.5	4.6	
		Control inputs	−0.5	4.6	
V _O	Voltage range applied to any output in the high-impedance or power-off state	A port	−0.5	4.6	V
		B port	−0.5	4.6	
V _O	Voltage range applied to any output in the high or low state	A port	−0.5	4.6	V
		B port	−0.5	4.6	
I _{IK}	Input clamp current	V _I < 0		−50	mA
I _{OK}	Output clamp current	V _O < 0		−50	mA
I _O	Continuous output current			±50	mA
	Continuous current through V _{CCA} or GND			±100	mA
T _{stg}	Storage temperature		−65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2500	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1500	
		Machine model (MM)	±250	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

See⁽¹⁾

			V_{CCA}	V_{CCB}	MIN	MAX	UNIT
V_{CCA}	Supply voltage				1.1	3.6	V
V_{CCB}	Supply voltage				1.1	3.6	V
V_{IH}	High-level input voltage	A-Port CMD and DATA I/Os	1.1 V to 1.95 V	1.1 V to 1.95 V	$V_{CCI} - 0.2$	V_{CCI}	V
		B-Port CMD and DATA I/Os	1.95 V to 3.6 V	1.95 V to 3.6 V			
		EN and CLKA	1.1 V to 3.6 V	1.1 V to 3.6 V	$V_{CCI} \times 0.65$	V_{CCI}	
V_{IL}	Low-level input voltage	A-Port CMD and DATA I/Os	1.1 V to 1.95 V	1.1 V to 1.95 V	0	0.15	V
		B-Port CMD and DATA I/Os	1.95 V to 3.6 V	1.95 V to 3.6 V			
		EN and CLKA	1.1 V to 3.6 V	1.1 V to 3.6 V	0	$V_{CCI} \times 0.35$	
V_O	Output voltage	Active state			0	V_{CCO}	V
		3-state			0	3.6	
I_{OH}	High-level output current (CLK-f output)		1.1 V to 3.6 V	1.1 V to 3.6 V		-100	μA
			1.1 V to 1.3 V			-0.5	mA
			1.4 V to 1.6 V			-1	
			1.65 V to 1.95 V			-2	
			2.3 V to 2.7 V			-4	
			3 V to 3.6 V			-8	
I_{OL}	Low-level output current (CLK-f output)		1.1 V to 3.6 V	1.1 V to 3.6 V		100	μA
			1.1 V to 1.3 V			0.5	mA
			1.4 V to 1.6 V			1	
			1.65 V to 1.95 V			2	
			2.3 V to 2.7 V			4	
			3 V to 3.6 V			8	
I_{OH}	High-level output current (CLK output)		1.1 V to 3.6 V	1.1 V to 3.6 V		-100	μA
				1.1 V to 1.3 V		-0.5	mA
				1.4 V to 1.6 V		-1	
				1.65 V to 1.95 V		-2	
				2.3 V to 2.7 V		-4	
				3 V to 3.6 V		-8	
I_{OL}	Low-level output current (CLK output)		1.1 V to 3.6 V	1.1 V to 3.6 V		100	μA
				1.1 V to 1.3 V		0.5	mA
				1.4 V to 1.6 V		1	
				1.65 V to 1.95 V		2	
				2.3 V to 2.7 V		4	
				3 V to 3.6 V		8	
$\Delta t/\Delta v$	Input transition rise or fall rate					5	ns/V
T_A	Operating free-air temperature				-40	85	°C

(1) All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, [SCBA004](#).

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TXS0206A	UNIT
		YFP (DSBGA)	
		20 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	71.1	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	0.5	°C/W
R _{θJB}	Junction-to-board thermal resistance	10.4	°C/W
ψ _{JT}	Junction-to-top characterization parameter	2	°C/W
ψ _{JB}	Junction-to-board characterization parameter	10.4	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CCA}	V _{CCB}	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{OH}	A port (CLK-f output)	I _{OH} = –100 μA	1.1 V to 3.6 V	1.65 V to 3.6 V	V _{CCA} × 0.8			V
		I _{OH} = –0.5 mA	1.1 V	1.65 V to 3.6 V	0.8			
		I _{OH} = –1 mA	1.4 V	1.65 V to 3.6 V	1.05			
		I _{OH} = –2 mA	1.65 V	1.65 V to 3.6 V	1.2			
		I _{OH} = –4 mA	2.3 V	1.65 V to 3.6 V	1.75			
		I _{OH} = –8 mA	3 V	1.65 V to 3.6 V	2.3			
	A port (DAT and CMD outputs)	I _{OH} = –20 μA	1.1 V to 3.6 V	1.65 V to 3.6 V	V _{CCA} × 0.8			
V _{OL}	A port (CLK-f output)	I _{OL} = 100 μA	1.1 V to 3.6 V	1.65 V to 3.6 V			V _{CCA} × 0.2	V
		I _{OL} = 0.5 mA	1.1 V	1.65 V to 3.6 V			0.35	
		I _{OL} = 1 mA	1.4 V	1.65 V to 3.6 V			0.35	
		I _{OL} = 2 mA	1.65 V	1.65 V to 3.6 V			0.45	
		I _{OL} = 4 mA	2.3 V	1.65 V to 3.6 V			0.55	
		I _{OL} = 8 mA	3 V	1.65 V to 3.6 V			0.7	
	A port (DAT and CMD outputs)	I _{OL} = 135 μA	1.1 V	1.65 V to 3.6 V			0.4	V
		I _{OL} = 180 μA	1.4 V	1.65 V to 3.6 V			0.4	
		I _{OL} = 220 μA	1.65 V	1.65 V to 3.6 V			0.4	
		I _{OL} = 300 μA	2.3 V	1.65 V to 3.6 V			0.4	
		I _{OL} = 400 μA	3 V	1.65 V to 3.6 V			0.55	
V _{OH}	B port (CLK output)	I _{OH} = –100 μA	1.1 V to 3.6 V	1.65 V to 3.6 V	V _{CCB} × 0.8			V
		I _{OH} = –2 mA	1.1 V to 3.6 V	1.65 V	1.2			
		I _{OH} = –4 mA	1.1 V to 3.6 V	2.3 V	1.75			
		I _{OH} = –8 mA	1.1 V to 3.6 V	3 V	2.3			
	B port (DAT output)	I _{OH} = –20 μA	1.1 V to 3.6 V	1.65 V to 3.6 V	V _{CCB} × 0.8			

(1) All typical values are at T_A = 25°C.

Electrical Characteristics (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CCA}	V _{CCB}	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{OL}	B port	I _{OL} = 100 μA	1.1 V to 3.6 V	1.65 V to 3.6 V	V _{CCB} × 0.2			V
		I _{OL} = 2 mA	1.1 V to 3.6 V	1.65 V	0.45			
		I _{OL} = 4 mA	1.1 V to 3.6 V	2.3 V	0.55			
		I _{OL} = 8 mA	1.1 V to 3.6 V	3 V	0.7			
	B port (DAT output)	I _{OL} = 135 μA	1.1 V to 3.6 V	1.65 V to 3.6 V	0.4		V	
		I _{OL} = 220 μA	1.1 V to 3.6 V	1.65 V	0.4			
		I _{OL} = 300 μA	1.1 V to 3.6 V	2.3 V	0.4			
		I _{OL} = 300 μA	1.1 V to 3.6 V	3 V	0.55			
I _I	Control inputs	V _I = V _{CCA} or GND	1.1 V to 3.6 V	1.65 V to 3.6 V	±1		μA	
I _{CCA}	A port	V _I = V _{CCI} , I _O = 0	1.1 V to 3.6 V	1.65 V to 3.6 V	7		μA	
I _{CCB}	B port	V _I = V _{CCI} , I _O = 0	1.1 V to 3.6 V	1.65 V to 3.6 V	11		μA	
C _{io}	A port				5.5	6.5	pF	
	B port				7	9.5		
C _i	Control inputs	V _I = V _{CCA} or GND			3.5	4.5	pF	
	Clock input	V _I = V _{CCA} or GND			3	4		

6.6 Timing Requirements—V_{CCA} = 1.2 V ± 0.1 V

over recommended operating free-air temperature range (unless otherwise noted)

			V _{CC}	MIN	MAX	UNIT
Data rate	Command	Push-pull driving	V _{CCB} = 1.8 V ± 0.15 V	40		Mbps
			V _{CCB} = 3.3 V ± 0.3 V	40		
		Open-drain driving	V _{CCB} = 1.8 V ± 0.15 V	1		
			V _{CCB} = 3.3 V ± 0.3 V	1		
	Clock	Push-pull driving	V _{CCB} = 1.8 V ± 0.15 V	40		MHz
			V _{CCB} = 3.3 V ± 0.3 V	40		
	Data		V _{CCB} = 1.8 V ± 0.15 V	40		Mbps
			V _{CCB} = 3.3 V ± 0.3 V	40		
t _w	Command	Push-pull driving	V _{CCB} = 1.8 V ± 0.15 V	25		ns
			V _{CCB} = 3.3 V ± 0.3 V	25		
		Open-drain driving	V _{CCB} = 1.8 V ± 0.15 V	1		μs
			V _{CCB} = 3.3 V ± 0.3 V	1		
	Clock	Push-pull driving	V _{CCB} = 1.8 V ± 0.15 V	10		ns
			V _{CCB} = 3.3 V ± 0.3 V	8.3		
	Data		V _{CCB} = 1.8 V ± 0.15 V	25		ns
			V _{CCB} = 3.3 V ± 0.3 V	25		

6.7 Timing Requirements— $V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$

over recommended operating free-air temperature range (unless otherwise noted)

			V_{CC}	MIN	MAX	UNIT
Data rate	Command	Push-pull driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		60	Mbps
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		60	
		Open-drain driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		1	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		1	
	Clock	Push-pull driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		60	MHz
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		60	
	Data	Push-pull driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		60	Mbps
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		60	
t_w Pulse duration	Command	Push-pull driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	17		ns
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	17		
		Open-drain driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	1		μs
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1		
	Clock	Push-pull driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	8.3		ns
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	8.3		
	Data	Push-pull driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	17		ns
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	17		

6.8 Timing Requirements— $V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$

over recommended operating free-air temperature range (unless otherwise noted)

			V_{CC}	MIN	MAX	UNIT
Data rate	Command	Push-pull driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		60	Mbps
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		60	
		Open-drain driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		1	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		1	
	Clock	Push-pull driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		55	MHz
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		55	
	Data	Push-pull driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		60	Mbps
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		60	
t_w Pulse duration	Command	Push-pull driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	17		ns
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	17		
		Open-drain driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	1		μs
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1		
	Clock	Push-pull driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	9		ns
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	9		
	Data	Push-pull driving	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	17		ns
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	17		

6.9 Switching Characteristics— $V_{CCA} = 1.2 \text{ V} \pm 0.1 \text{ V}$

over operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC}	MIN	MAX	UNIT
t _{pd}	CMDA	CMDB	V _{CCB} = 1.8 V ± 0.15 V		5.7	ns
			V _{CCB} = 3.3 V ± 0.3 V		4.4	
	CMDB	CMDA	V _{CCB} = 1.8 V ± 0.15 V		6.7	
			V _{CCB} = 3.3 V ± 0.3 V		5.8	
	CLKA	CLKB	V _{CCB} = 1.8 V ± 0.15 V		6.2	
			V _{CCB} = 3.3 V ± 0.3 V		4.5	
	DATxA	DATxB	V _{CCB} = 1.8 V ± 0.15 V		7.6	
			V _{CCB} = 3.3 V ± 0.3 V		7.5	
	DATxB	DATxA	V _{CCB} = 1.8 V ± 0.15 V		6.3	
			V _{CCB} = 3.3 V ± 0.3 V		4.6	
CLKA	CLK-f	V _{CCB} = 1.8 V ± 0.15 V		12		
		V _{CCB} = 3.3 V ± 0.3 V		7.9		
t _{en}	EN	B-port	V _{CCB} = 1.8 V ± 0.15 V		1	μs
			V _{CCB} = 3.3 V ± 0.3 V		1	
	EN	A-port	V _{CCB} = 1.8 V ± 0.15 V		1	
			V _{CCB} = 3.3 V ± 0.3 V		1	
t _{dis}	EN	B-port	V _{CCB} = 1.8 V ± 0.15 V		412	ns
			V _{CCB} = 3.3 V ± 0.3 V		363	
	EN	A-port	V _{CCB} = 1.8 V ± 0.15 V		423	
			V _{CCB} = 3.3 V ± 0.3 V		422	
t _{rA}	CMDA rise time		V _{CCB} = 1.8 V ± 0.15 V	3.5	8.4	ns
			V _{CCB} = 3.3 V ± 0.3 V	3.4	8.1	
	CLK-f rise time		V _{CCB} = 1.8 V ± 0.15 V	1	4.7	
			V _{CCB} = 3.3 V ± 0.3 V	1	4.1	
	DATxA rise time		V _{CCB} = 1.8 V ± 0.15 V	3.5	8.4	
			V _{CCB} = 3.3 V ± 0.3 V	3.4	8.1	
t _{rB}	CMDB rise time		V _{CCB} = 1.8 V ± 0.15 V	1.4	6.5	ns
			V _{CCB} = 3.3 V ± 0.3 V	0.6	3.1	
	CLKB rise time		V _{CCB} = 1.8 V ± 0.15 V	0.6	5.9	
			V _{CCB} = 3.3 V ± 0.3 V	0.5	4.3	
	DATxB rise time		V _{CCB} = 1.8 V ± 0.15 V	1.4	10.9	
			V _{CCB} = 3.3 V ± 0.3 V	0.6	5	
t _{fA}	CMDA fall time		V _{CCB} = 1.8 V ± 0.15 V	2.4	5.7	ns
			V _{CCB} = 3.3 V ± 0.3 V	2	5.1	
	CLK-f fall time		V _{CCB} = 1.8 V ± 0.15 V	0.8	2.5	
			V _{CCB} = 3.3 V ± 0.3 V	0.8	3	
	DATxA fall time		V _{CCB} = 1.8 V ± 0.15 V	2.4	5.7	
			V _{CCB} = 3.3 V ± 0.3 V	1.9	5.1	
t _{fB}	CMDB fall time		V _{CCB} = 1.8 V ± 0.15 V	1.2	5.4	ns
			V _{CCB} = 3.3 V ± 0.3 V	0.6	3.6	
	CLKB fall time		V _{CCB} = 1.8 V ± 0.15 V	0.6	6.3	
			V _{CCB} = 3.3 V ± 0.3 V	0.5	4	
	DATxB fall time		V _{CCB} = 1.8 V ± 0.15 V	0.6	6.3	
			V _{CCB} = 3.3 V ± 0.3 V	0.5	3.6	
t _{SK(O)}	Channel-to-channel skew		V _{CCB} = 1.8 V ± 0.15 V		1	ns
			V _{CCB} = 3.3 V ± 0.3 V		1	

Switching Characteristics— $V_{CCA} = 1.2 \text{ V} \pm 0.1 \text{ V}$ (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC}	MIN	MAX	UNIT
Max data rate	Command	Push-pull driving	V _{CCB} = 1.8 V ± 0.15 V		40	Mbps
			V _{CCB} = 3.3 V ± 0.3 V		40	
		Open-drain driving	V _{CCB} = 1.8 V ± 0.15 V		1	
			V _{CCB} = 3.3 V ± 0.3 V		1	
	Clock		V _{CCB} = 1.8 V ± 0.15 V		40	MHz
			V _{CCB} = 3.3 V ± 0.3 V		60	
	Data		V _{CCB} = 1.8 V ± 0.15 V		40	Mbps
			V _{CCB} = 3.3 V ± 0.3 V		40	

6.10 Switching Characteristics— $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$

over operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC}	MIN	MAX	UNIT
t _{pd}	CMDA	CMDB	V _{CCB} = 1.8 V ± 0.15 V		4.9	ns
			V _{CCB} = 3.3 V ± 0.3 V		3.3	
	CMDB	CMDA	V _{CCB} = 1.8 V ± 0.15 V		5.6	
			V _{CCB} = 3.3 V ± 0.3 V		3.6	
	CLKA	CLKB	V _{CCB} = 1.8 V ± 0.15 V		5.4	
			V _{CCB} = 3.3 V ± 0.3 V		3.4	
	DATxA	DATxB	V _{CCB} = 1.8 V ± 0.15 V		5	
			V _{CCB} = 3.3 V ± 0.3 V		4.4	
	DATxB	DATxA	V _{CCB} = 1.8 V ± 0.15 V		5.4	
			V _{CCB} = 3.3 V ± 0.3 V		3.5	
CLKA	CLK-f	V _{CCB} = 1.8 V ± 0.15 V		10.2		
		V _{CCB} = 3.3 V ± 0.3 V		5.7		
t _{en}	EN	B-port	V _{CCB} = 1.8 V ± 0.15 V		1	μs
			V _{CCB} = 3.3 V ± 0.3 V		1	
	EN	A-port	V _{CCB} = 1.8 V ± 0.15 V		1	
			V _{CCB} = 3.3 V ± 0.3 V		1	
t _{dis}	EN	B-port	V _{CCB} = 1.8 V ± 0.15 V		411	ns
			V _{CCB} = 3.3 V ± 0.3 V		411	
	EN	A-port	V _{CCB} = 1.8 V ± 0.15 V		413	
			V _{CCB} = 3.3 V ± 0.3 V		361	
t _{rA}	CMDA rise time		V _{CCB} = 1.8 V ± 0.15 V	2.1	4.5	ns
			V _{CCB} = 3.3 V ± 0.3 V	2.1	4.1	
	CLK-f rise time		V _{CCB} = 1.8 V ± 0.15 V	0.6	2.5	
			V _{CCB} = 3.3 V ± 0.3 V	0.6	2.3	
	DATxA rise time		V _{CCB} = 1.8 V ± 0.15 V	1.8	4.5	
			V _{CCB} = 3.3 V ± 0.3 V	1.8	4.2	
t _{rB}	CMDB rise time		V _{CCB} = 1.8 V ± 0.15 V	1.4	6.6	ns
			V _{CCB} = 3.3 V ± 0.3 V	0.7	3.8	
	CLKB rise time		V _{CCB} = 1.8 V ± 0.15 V	0.5	5.8	
			V _{CCB} = 3.3 V ± 0.3 V	0.5	4.4	
	DATxB rise time		V _{CCB} = 1.8 V ± 0.15 V	1.4	10.8	
			V _{CCB} = 3.3 V ± 0.3 V	0.7	8	

Switching Characteristics— $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC}	MIN	MAX	UNIT
t_{fA}	CMDA fall time		$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$	0.4	3.4	ns
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$	0.3	2.9	
	CLK-f fall time		$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$	0.3	2.8	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$	0.3	2.8	
	DATxA fall time		$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$	0.4	3.4	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$	0.3	2.9	
t_{fB}	CMDB fall time		$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$	1.1	6.3	ns
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$	0.6	3.7	
	CLKB fall time		$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$	0.6	8.7	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$	0.5	4.1	
	DATxB fall time		$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$	1.2	7	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$	0.2	4	
$t_{SK(O)}$	Channel-to-channel skew		$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		1	ns
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		1	
Max data rate	Command	Push-pull driving	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		60	Mbps
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		60	
		Open-drain driving	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		1	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		1	
	Clock		$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		60	MHz
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		60	
	Data		$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		60	Mbps
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		60	

6.11 Switching Characteristics— $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC}	MIN	MAX	UNIT
t_{pd}	CMDA	CMDB	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		5.3	ns
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		3.2	
	CMDB	CMDA	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		5.1	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		3	
	CLKA	CLKB	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		4.8	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		3.1	
	DATxA	DATxB	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		5.1	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		3.2	
	DATxB	DATxA	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		9.6	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		5.1	
	CLKA	CLK-f	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		6.8	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4.2	
t_{en}	EN	B-port	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		1	μs
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		1	
	EN	A-port	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		1	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		1	
t_{dis}	EN	B-port	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		410	ns
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		364	
	EN	A-port	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		396	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		398	

Switching Characteristics— $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC}	MIN	MAX	UNIT
t _{rA}	CMDA rise time		V _{CCB} = 1.8 V ± 0.15 V	1.4	4.2	ns
			V _{CCB} = 3.3 V ± 0.3 V	1.4	4.2	
	CLK-f rise time		V _{CCB} = 1.8 V ± 0.15 V	0.5	1.5	
			V _{CCB} = 3.3 V ± 0.3 V	0.5	1.4	
	DATxA rise time		V _{CCB} = 1.8 V ± 0.15 V	1.4	3.4	
			V _{CCB} = 3.3 V ± 0.3 V	1.3	3	
t _{rB}	CMDB rise time		V _{CCB} = 1.8 V ± 0.15 V	1.4	6.4	ns
			V _{CCB} = 3.3 V ± 0.3 V	0.9	4	
	CLKB rise time		V _{CCB} = 1.8 V ± 0.15 V	0.6	5.9	
			V _{CCB} = 3.3 V ± 0.3 V	0.5	4.4	
	DATxB rise time		V _{CCB} = 1.8 V ± 0.15 V	1.4	14	
			V _{CCB} = 3.3 V ± 0.3 V	0.9	14	
t _{fA}	CMDA fall time		V _{CCB} = 1.8 V ± 0.15 V	0.8	2.3	ns
			V _{CCB} = 3.3 V ± 0.3 V	0.8	2.3	
	CLK-f fall time		V _{CCB} = 1.8 V ± 0.15 V	0.4	1.3	
			V _{CCB} = 3.3 V ± 0.3 V	0.4	1.3	
	DATxA fall time		V _{CCB} = 1.8 V ± 0.15 V	0.8	2.2	
			V _{CCB} = 3.3 V ± 0.3 V	0.7	2	
t _{rB}	CMDB fall time		V _{CCB} = 1.8 V ± 0.15 V	0.8	6.2	ns
			V _{CCB} = 3.3 V ± 0.3 V	0.8	5	
	CLKB fall time		V _{CCB} = 1.8 V ± 0.15 V	0.6	7.8	
			V _{CCB} = 3.3 V ± 0.3 V	0.5	4.3	
	DATxB fall time		V _{CCB} = 1.8 V ± 0.15 V	0.7	6.8	
			V _{CCB} = 3.3 V ± 0.3 V	0.6	5	
t _{SK(O)}	Channel-to-channel skew		V _{CCB} = 1.8 V ± 0.15 V		1	ns
			V _{CCB} = 3.3 V ± 0.3 V		1	
Max data rate	Command	Push-pull driving	V _{CCB} = 1.8 V ± 0.15 V		60	Mbps
			V _{CCB} = 3.3 V ± 0.3 V		60	
		Open-drain driving	V _{CCB} = 1.8 V ± 0.15 V		1	
			V _{CCB} = 3.3 V ± 0.3 V		1	
	Clock		V _{CCB} = 1.8 V ± 0.15 V		55	MHz
			V _{CCB} = 3.3 V ± 0.3 V		55	
	Data		V _{CCB} = 1.8 V ± 0.15 V		60	Mbps
			V _{CCB} = 3.3 V ± 0.3 V		60	

6.12 Operating Characteristics — $V_{CCA} = 1.2 \text{ V}$
 $T_A = 25^\circ\text{C}$

PARAMETER			TEST CONDITIONS	V _{CCB} TYP		UNIT
				1.8 V	3.3 V	
C _{pdA} ⁽¹⁾	A-port input, B-port output	CLK Enabled	C _L = 0, f = 10 MHz, t _r = t _f = 1 ns	15.1	15	pF
		DATA Enabled		9.26	9.19	
	B-port input, A-port output	DATA Enabled		12.4	11.9	
	A-port input, B-port output	CLK Disabled		0.1	0.1	
		DATA Disabled		1.3	1.3	
	B-port input, A-port output	DATA Disabled		0.1	0.1	

(1) Power dissipation capacitance per transceiver.

Operating Characteristics — $V_{CCA} = 1.2\text{ V}$ (continued)

 $T_A = 25^\circ\text{C}$

PARAMETER			TEST CONDITIONS	V_{CCB} TYP		UNIT
				1.8 V	3.3 V	
$C_{pdB}^{(1)}$	A-port input, B-port output	DATA Enabled	$C_L = 0$, $f = 10\text{ MHz}$, $t_r = t_f = 1\text{ ns}$	26.7	30.3	pF
		CLK Enabled		25.6	27	
	B-port input, A-port output	DATA Enabled		16.38	19.91	
		DATA Disabled		0.1	0.1	
	B-port input, A-port output	CLK Disabled		0.1	0.1	
		DATA Disabled		1.1	0.8	

6.13 Operating Characteristics — $V_{CCA} = 1.8\text{ V}$

 $T_A = 25^\circ\text{C}$

PARAMETER			TEST CONDITIONS	V_{CCB} TYP		UNIT
				1.8 V	3.3 V	
$C_{pdA}^{(1)}$	A-port input, B-port output	CLK Enabled	$C_L = 0$, $f = 10\text{ MHz}$, $t_r = t_f = 1\text{ ns}$	17.5	17.1	pF
		DATA Enabled		9.96	9.82	
	B-port input, A-port output	DATA Enabled		15.6	14	
		CLK Disabled		0.1	0.1	
	B-port input, A-port output	DATA Disabled		1.3	1.3	
		DATA Disabled		0.1	0.1	
$C_{pdB}^{(1)}$	A-port input, B-port output	DATA Enabled	$C_L = 0$, $f = 10\text{ MHz}$, $t_r = t_f = 1\text{ ns}$	26	28.5	pF
		CLK Enabled		25.8	27	
	B-port input, A-port output	DATA Enabled		16.69	19.6	
		DATA Disabled		0.1	0.1	
	B-port input, A-port output	CLK Disabled		0.1	0.1	
		DATA Disabled		1.1	0.8	

(1) Power dissipation capacitance per transceiver.

6.14 Operating Characteristics — $V_{CCA} = 3.3\text{ V}$

 $T_A = 25^\circ\text{C}$

PARAMETER			TEST CONDITIONS	V_{CCB} TYP		UNIT
				1.8 V	3.3 V	
$C_{pdA}^{(1)}$	A-port input, B-port output	CLK Enabled	$C_L = 0$, $f = 10\text{ MHz}$, $t_r = t_f = 1\text{ ns}$	17.5	17.1	pF
		DATA Enabled		12.50	13.29	
	B-port input, A-port output	DATA Enabled		15.6	14	
		CLK Disabled		0.1	0.1	
	B-port input, A-port output	DATA Disabled		1.3	1.3	
		DATA Disabled		0.1	0.1	

(1) Power dissipation capacitance per transceiver.

Operating Characteristics — $V_{CCA} = 3.3 \text{ V}$ (continued)

 $T_A = 25^\circ\text{C}$

PARAMETER			TEST CONDITIONS	$V_{CCB} \text{ TYP}$		UNIT
				1.8 V	3.3 V	
$C_{pdB}^{(1)}$	A-port input, B-port output	DATA Enabled	$C_L = 0$, $f = 10 \text{ MHz}$, $t_r = t_f = 1 \text{ ns}$	26	28.5	pF
	B-port input, A-port output	CLK Enabled		25.8	27	
		DATA Enabled		16.67	19.92	
	A-port input, B-port output	DATA Disabled		0.1	0.1	
	B-port input, A-port output	CLK Disabled		0.1	0.1	
		DATA Disabled		1.1	0.8	

6.15 Typical Characteristics

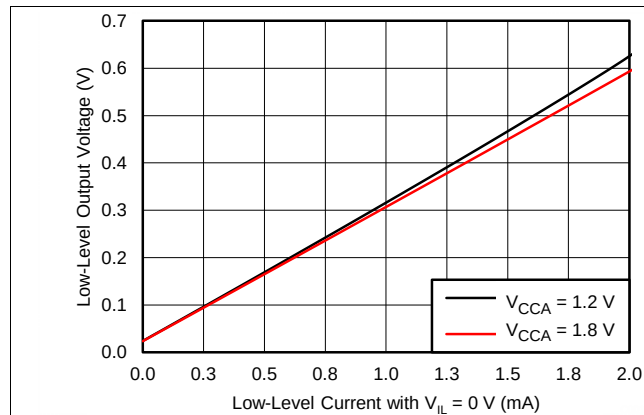


Figure 1. Low-Level Output Voltage (VOL(DATxB)) vs Low-Level Current (IOL(DATxA))

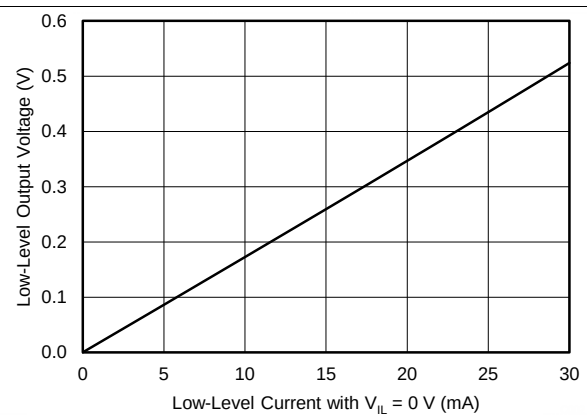
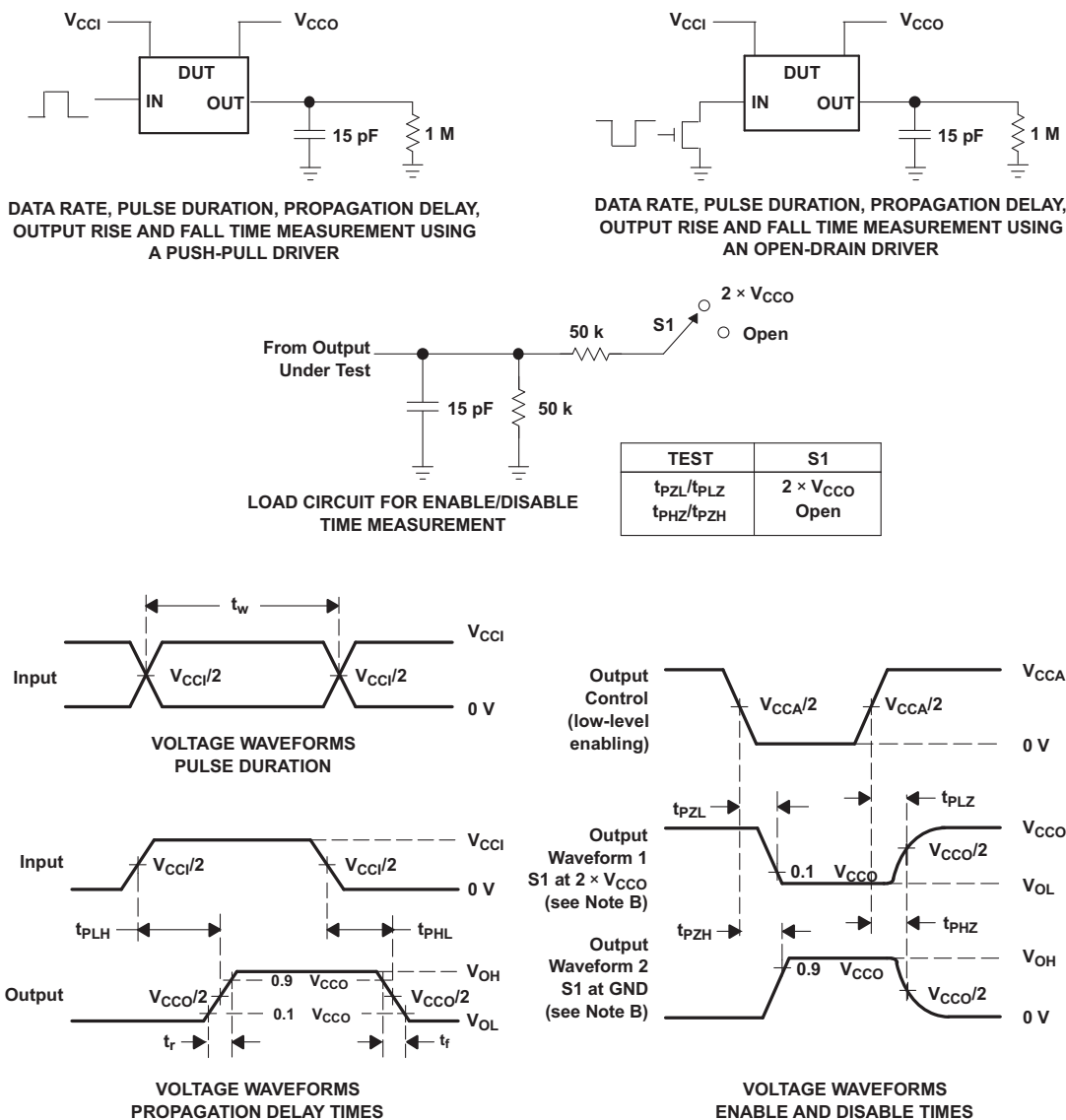


Figure 2. Low-Level Output Voltage (CLKB) vs Low-Level Current (CLKA)

7 Parameter Measurement Information



- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR = 10 MHz, $Z_O = 50 \Omega$, $dv/dt \geq 1$ V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PHZ} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. V_{CCI} is the V_{CC} associated with the input port.
- I. V_{CCO} is the V_{CC} associated with the output port.
- J. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

Feature Description (continued)

The edge-rate acceleration circuitry speeds up the output slew rate by monitoring the input edge for transitions, helping maintain the data rate through the device.

During a low-to-high signal rising-edge, the O.S. circuits turn on the PMOS transistors (T_1 , T_3) and its associated driver output resistance of the driver is decreased to approximately $50\ \Omega$ to $70\ \Omega$ during this acceleration phase to increase the current drive capability of the driver for approximately 30 ns or 95% of the input edge, whichever occurs first. This edge-rate acceleration provides high ac drive by bypassing the internal pullup resistors during the low-to-high transition to speed up the rising-edge signal.

During a high-to-low signal falling-edge, the O.S. circuits turn on the NMOS transistors (T_2 , T_4) and its associated driver output resistance of the driver is decreased to approximately $50\ \Omega$ to $70\ \Omega$ during this acceleration phase to increase the current drive capability of the driver for approximately 30 ns or 95% of the input edge, whichever occurs first.

To minimize dynamic I_{CC} and the possibility of signal contention, the user should wait for the O.S. circuit to turn-off before applying a signal in the opposite direction. The worst-case duration is equal to the minimum pulse-width number provided in the [Timing Requirements— \$V_{CCA} = 1.2\ V \pm 0.1\ V\$](#) section of this data sheet.

Once the O.S. is triggered and switched off, both the A and B ports must go to the same state (i.e. both High or both Low) for the one-shot to trigger again. In a DC state, the output drivers maintain a Low state through the pass transistor. The output drivers maintain a High through the "smart pullup resistors" that dynamically change value based on whether a Low or a High is being passed through the SDIO lines, as follows:

- R_1 and R_2 values are a nominal $40\ k\Omega$ when the output is driving a low
- R_1 and R_2 values are a nominal $4\ k\Omega$ when the output is driving a high
- R_1 and R_2 values are a nominal $40\ k\Omega$ when the device is disabled via the EN pin or by pulling the either V_{CCA} or V_{CCB} to 0 V.
- The threshold at which the resistance changes is approximately $V_{CCx}/2$

The reason for using these "smart" pullup resistors is to allow the TXS0206 to realize a lower static power consumption (when the I/Os are low), support lower V_{OL} values for the same size pass-gate transistor, and improved simultaneous switching performance.

8.4 Device Functional Modes

[Table 1](#) lists the functional modes of the TXS0206A.

Table 1. Function Table

EN	TRANSLATOR I/Os
L	Disabled, pulled to V_{CCA} , V_{CCB} through $40\ k\Omega$
H	Active

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

Systems engineers working with SD and MMC memory cards face a dilemma. These cards operate at a higher voltage node than the latest multimedia application processors, which have moved to smaller process technology nodes that support a maximum I/O interface voltage of 1.2 V. The problem is bridging the gap between these two voltage nodes while maintaining digital switching compatibility. The TXS0206A was designed specifically to address this. It is an auto direction sensing voltage level shifter that can interface with high speed SD and MMC cards because it supports a clock frequency of up to 60 MHz and each data channel supports up to 60 Mbps.

9.2 Typical Application

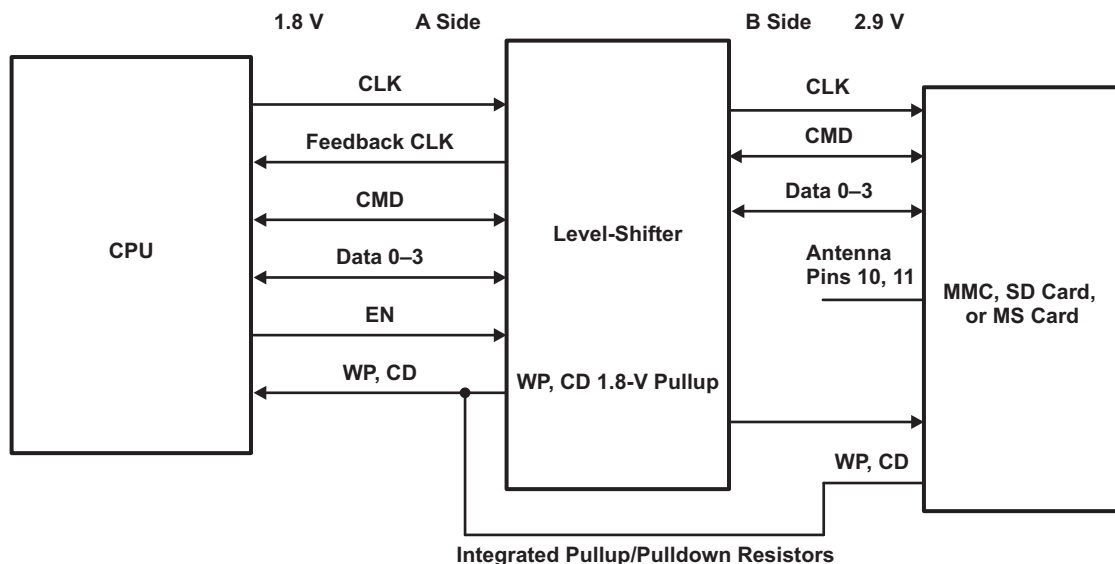


Figure 5. Typical Application Circuit

9.2.1 Design Requirements

For this design example, use the parameters listed in [Table 2](#)

Table 2. Design Parameters

PARAMETERS	VALUES
Input voltage	1.1 V to 3.6 V
Output voltage	1.1 V to 3.6 V

9.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
 - Use the supply voltage of the microprocessor that is driving the TXS0206A to determine the input voltage range. For a valid logic high, the value must exceed the V_{IH} of the input port. For a valid logic low, the value must be less than the V_{IL} of the input port.
- Output voltage range

- Use the supply voltage of the memory card that the TXS0206A is driving to determine the output voltage range.

9.2.2.1 External Pulldown Resistors

When using the TXS0206A device with MMCs, SD, and Memory Stick™ to ensure that a valid receiver input voltage high (V_{IH}) is achieved, the value of any pulldown resistors (external or internal to a memory card) must not be smaller than a 10-k Ω value. The impact of adding too heavy (less than 10-k Ω value) a pulldown resistor to the data and command lines of the TXS0206A device and the resulting 4-k Ω pullup / 10-k Ω pulldown voltage divider network has a direct impact on the V_{IH} of the signal being sent into the memory card and its associated logic.

The resulting V_{IH} voltage for the 10-k Ω pulldown resistor value would be:

$$V_{CC} \times 10 \text{ k}\Omega / (10 \text{ k}\Omega + 4 \text{ k}\Omega) = 0.714 \times V_{CC}$$

This is marginally above a valid input high voltage for a 1.8-V signal (i.e., $0.65 \times V_{CC}$).

The resulting V_{IH} voltage for 20-k Ω pulldown resistor value would be:

$$V_{CC} \times 20 \text{ k}\Omega / (20 \text{ k}\Omega + 4 \text{ k}\Omega) = 0.833 \times V_{CC}$$

Which is above the valid input high voltage for a 1.8-V signal of $0.65 \times V_{CC}$.

9.2.3 Application Curves

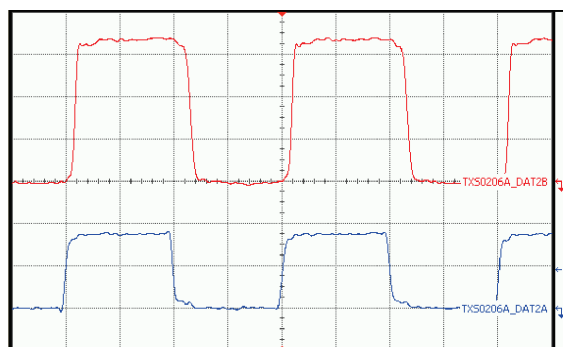
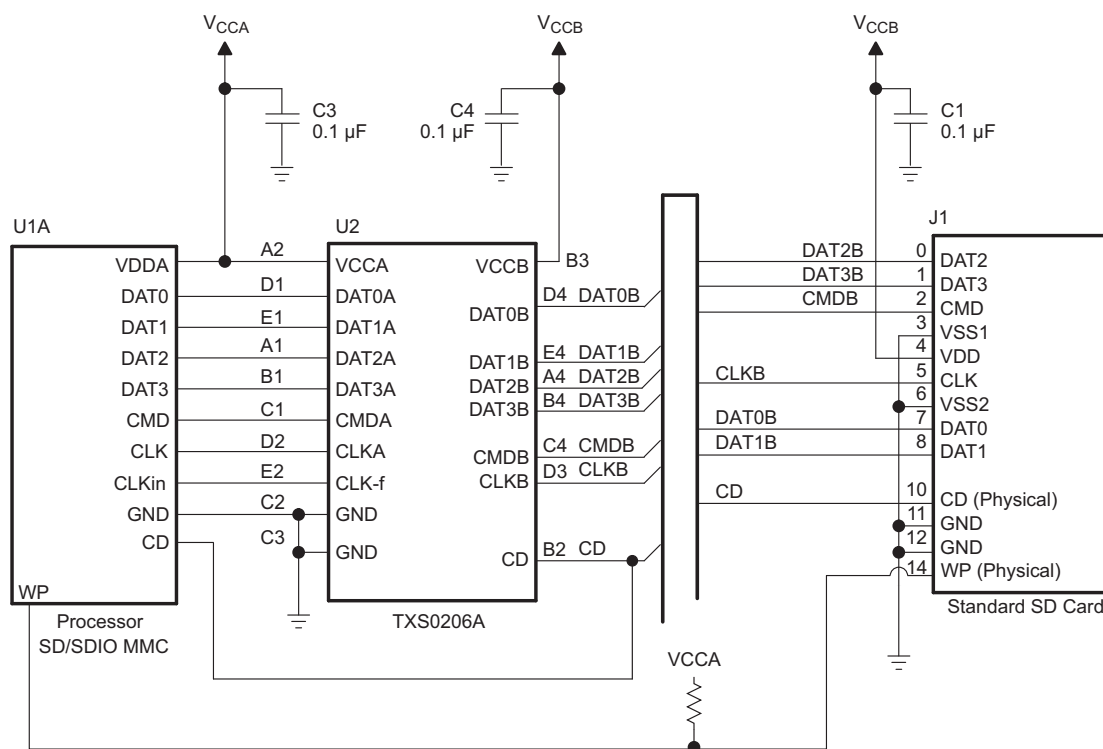
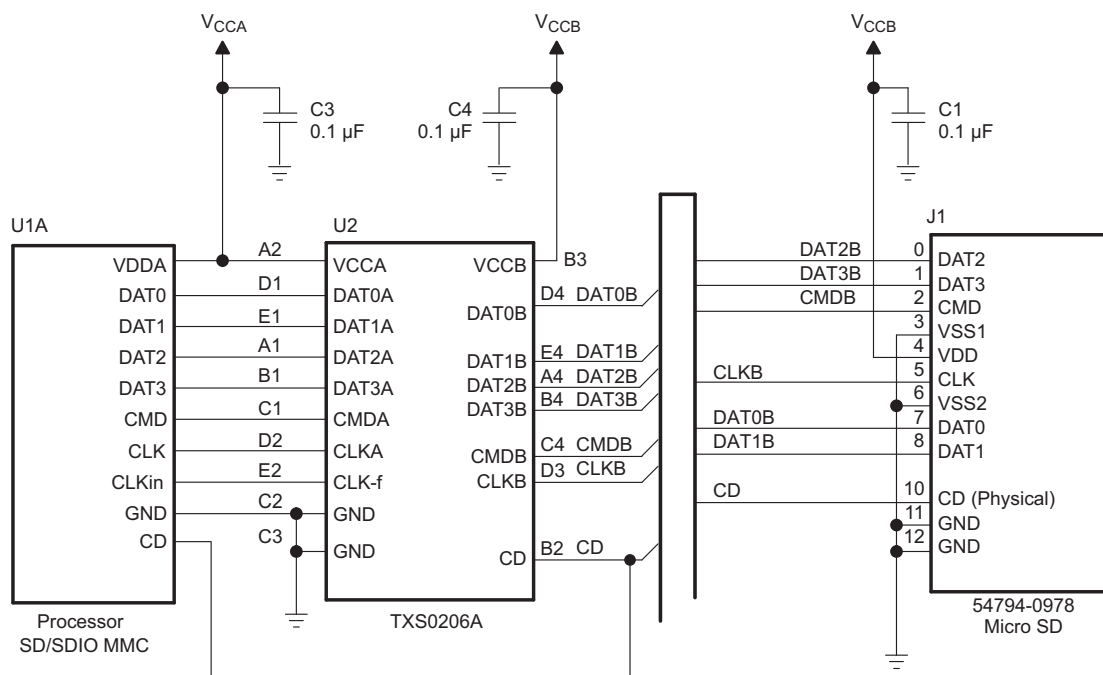


Figure 6. 1.8 V to 3.3 V Translation at 25 MHz



System Examples (continued)

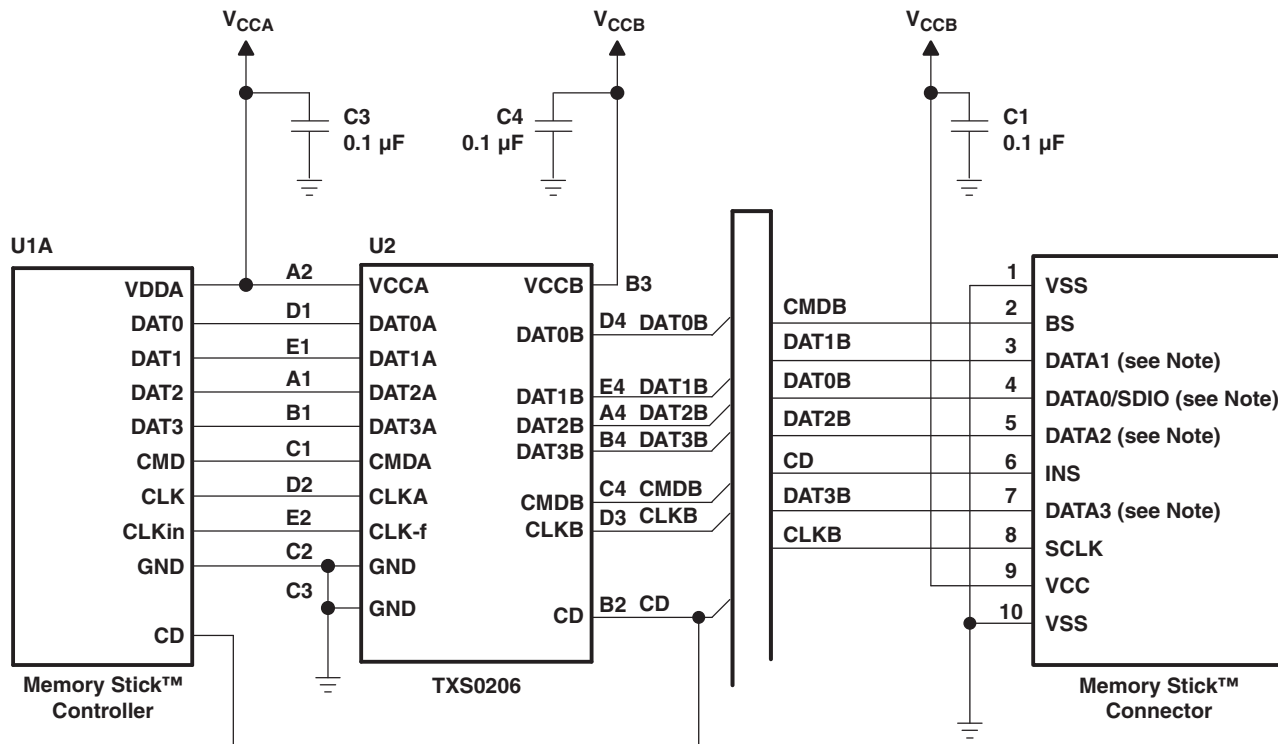


Figure 9. Interfacing With Memory Stick™ Card

10 Power Supply Recommendations

The TXS0206A does not require power sequencing between V_{CCA} and V_{CCB} during power-up so the power-supply rails can be ramped in any order.

The EN pin is referenced to V_{CCA} and when configured to low, will place all outputs into a high-impedance state. To ensure the high-impedance state of the outputs during power up or power down, the EN pin must be tied to GND through a pulldown resistor and must not be enabled until V_{CCA} and V_{CCB} are fully ramped and stable. The minimum value of the pulldown resistor to ground is determined by the current-sourcing capability of the driver controlling the EN pin.

Finally, the EN pin may be shorted to V_{CCA} if the application does not require use of the high-impedance state at any time.

11 Layout

11.1 Layout Guidelines

To ensure reliability of the device, TI recommends following common printed-circuit board layout guidelines.

- Bypass capacitors should be used on power supplies.
- Short trace lengths should be used to avoid excessive loading
- PCB signal trace-lengths must be kept short enough so that the round-trip delay of any reflection is less than the one shot duration, approximately 30 ns, ensuring that any reflection encounters low impedance at the source driver
- With very heavy capacitive loads, the one-shot can time-out before the signal is driven fully to the positive rail, so it is recommended that this lumped-load capacitance be considered and kept below 50 pF to avoid O.S. retriggering, bus contention, output signal oscillations, or other adverse system-level affects.

11.2 Layout Example

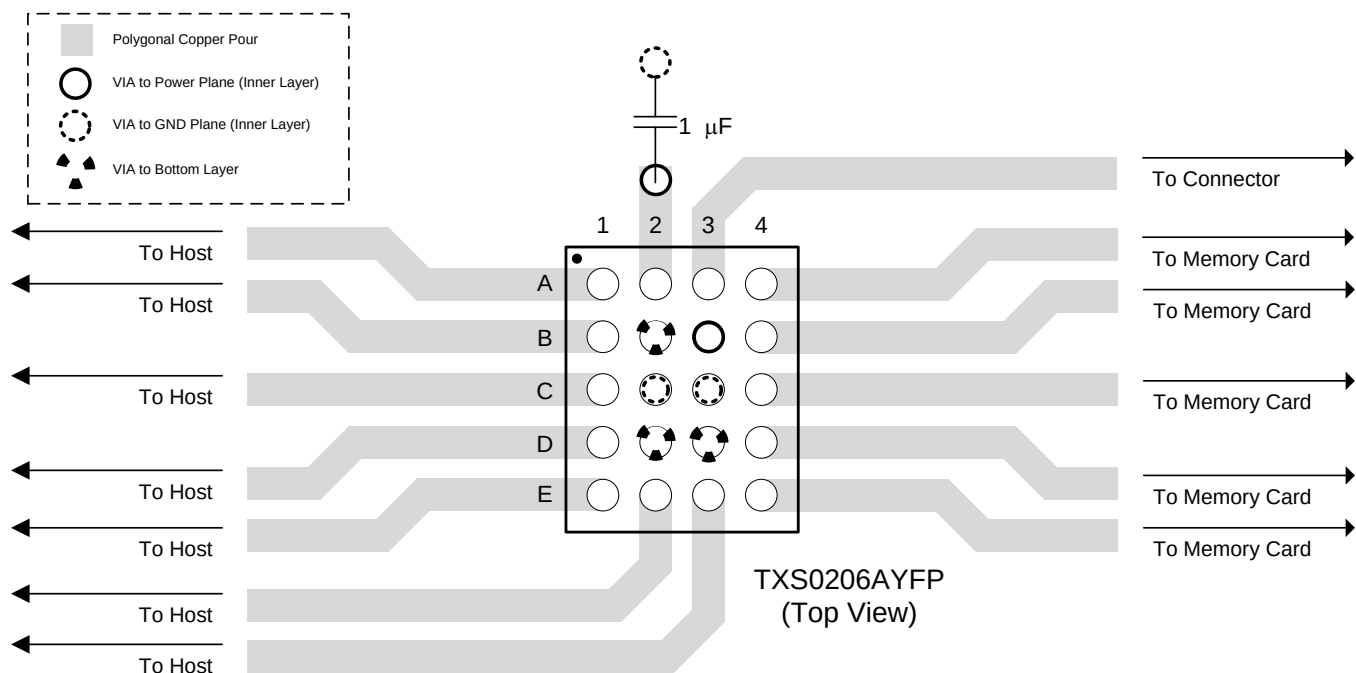


Figure 10. TXS0206A Example Layout (Top Layer)

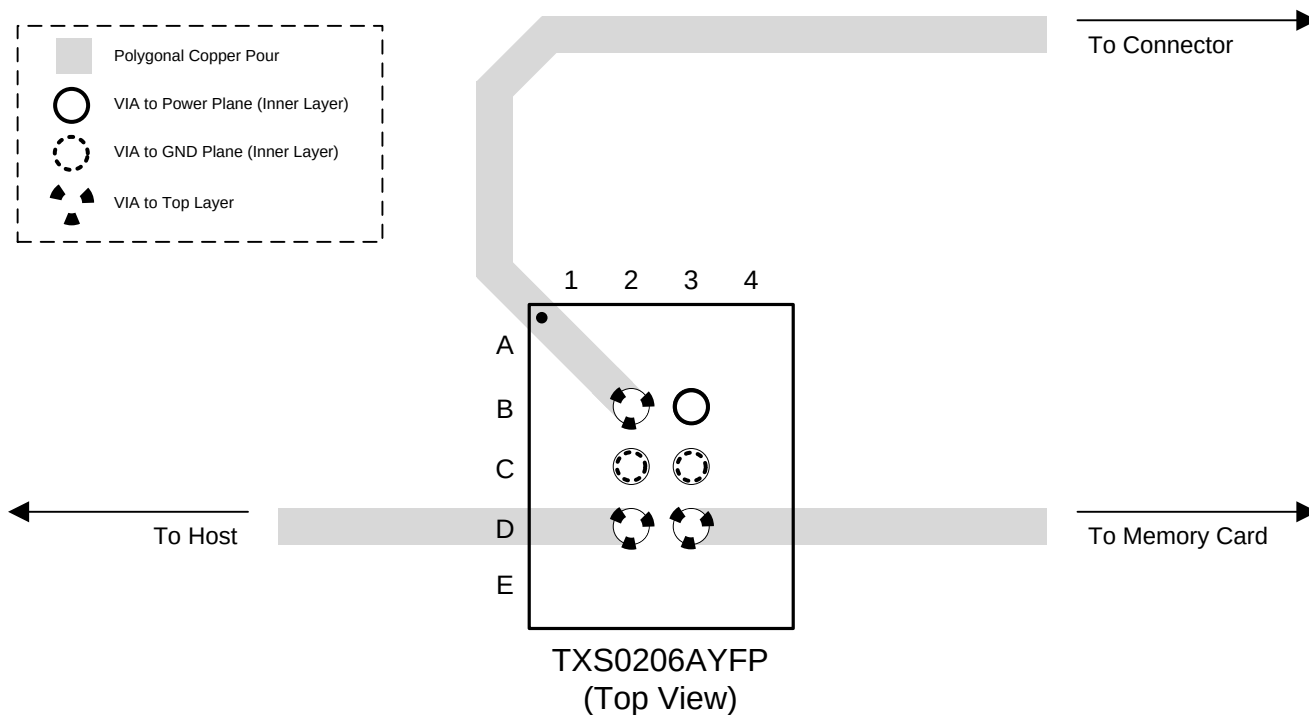


Figure 11. TXS0206A Example Layout (Bottom Layer)

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:

- *Introduction to Logic*, [SLVA700](#).
- *TXS0206A Evaluation Module*, [SCEU008](#).

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TXS0206AYFPR	Active	Production	DSBGA (YFP) 20	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	TXS0206A
TXS0206AYFPR.B	Active	Production	DSBGA (YFP) 20	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	TXS0206A

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

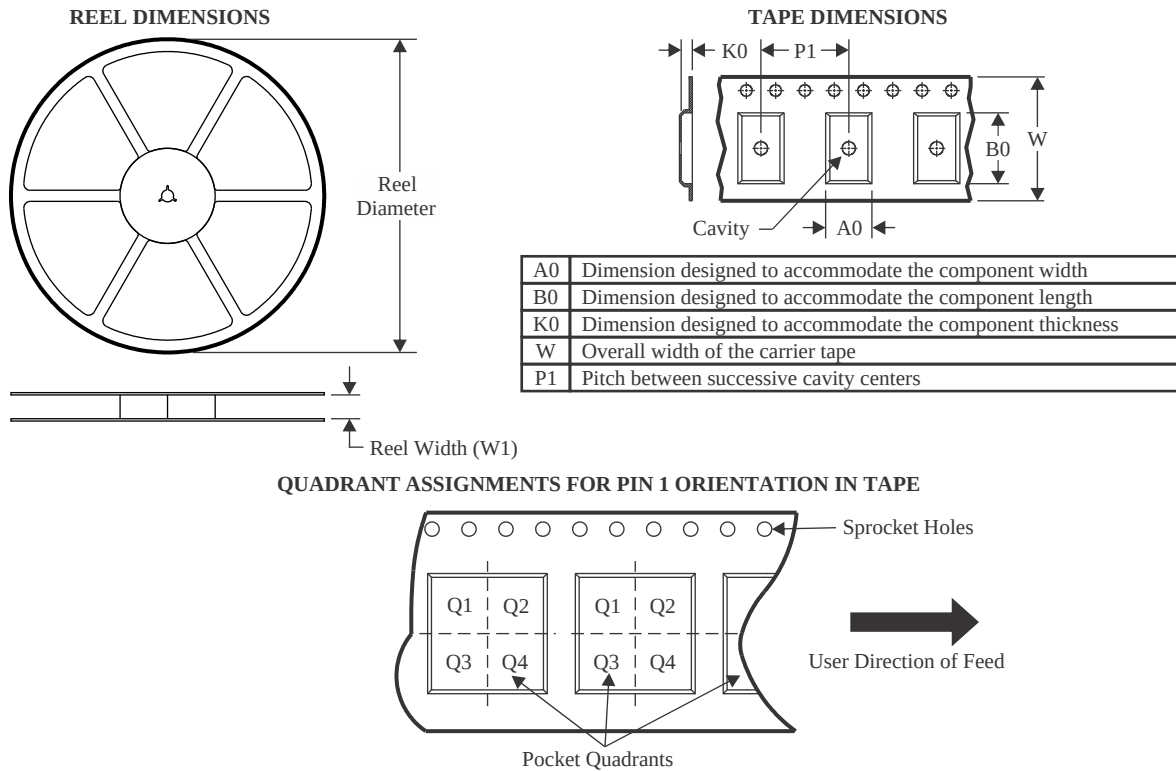
⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TXS0206AYFPR	DSBGA	YFP	20	3000	180.0	8.4	1.66	2.06	0.56	4.0	8.0	Q1

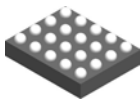
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TXS0206AYFPR	DSBGA	YFP	20	3000	182.0	182.0	20.0

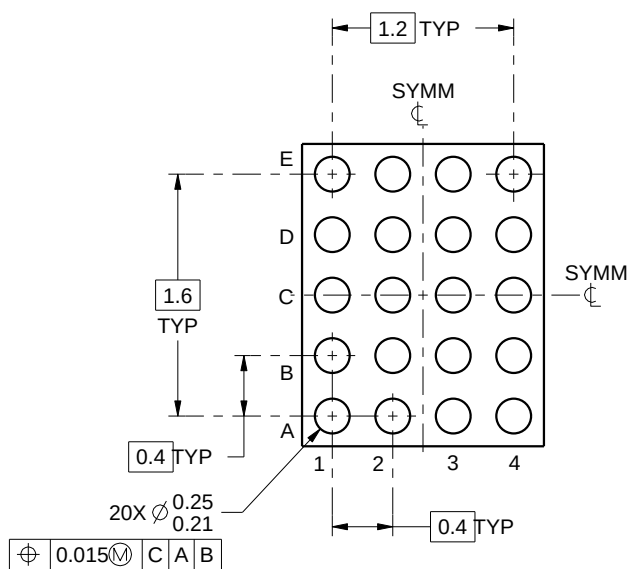
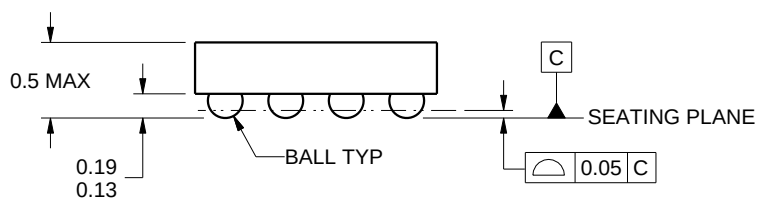
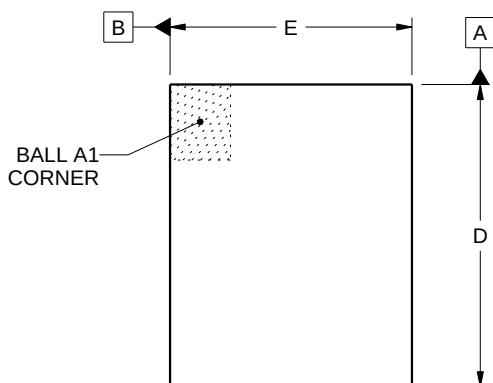
YFP0020



PACKAGE OUTLINE

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



D: Max = 1.988 mm, Min = 1.928 mm
E: Max = 1.588 mm, Min = 1.527 mm

4222895/A 04/2016

NOTES:

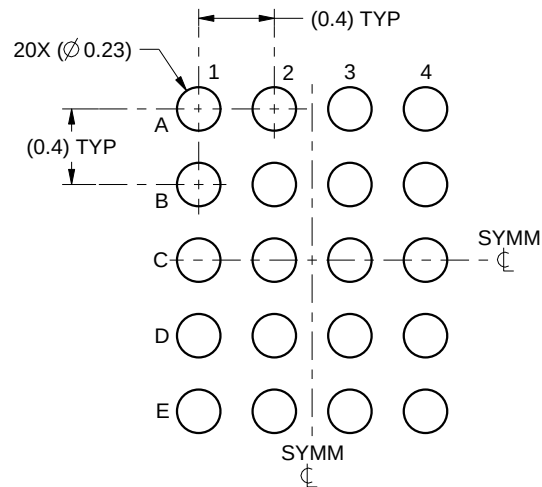
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

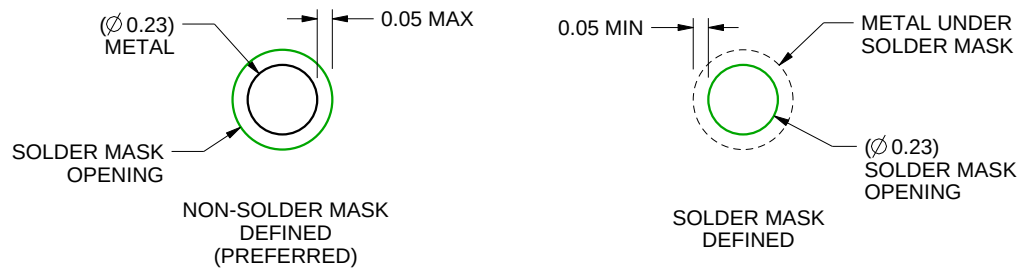
YFP0020

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE
SCALE:25X

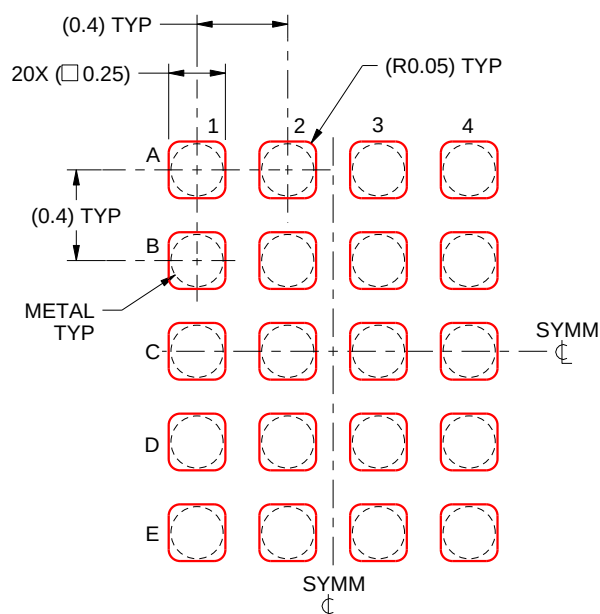


SOLDER MASK DETAILS
NOT TO SCALE

4222895/A 04/2016

NOTES: (continued)

- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



SOLDER PASTE EXAMPLE
 BASED ON 0.1 mm THICK STENCIL
 SCALE:30X

4222895/A 04/2016

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#), [TI's General Quality Guidelines](#), or other applicable terms available either on [ti.com](#) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2025, Texas Instruments Incorporated

Last updated 10/2025